

**DC-DC Boost & Buzzer Driver
SLG47105**

This application note describes how to create a Piezo Driver and Boost DC-DC Converter using one HVPAK SLG47105.

The application note comes complete with design files which can be found in the Reference section.

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1. Terms and Definitions

DFF	D Flip-Flop
HV	High Voltage
LUT	Look-up Table
MF	Multi-function
OSC	Oscillator

2. References

For related documents and software, please visit: [HVPAK™ | Renesas](#)

Download our free Go Configure Software Hub [1] to open the .hvp files [2] and view the proposed circuit design. Use the GreenPAK development tools [3] to freeze the design into your own customized IC in a matter of minutes. Find out more in a complete library of application notes [4] featuring design examples as well as explanations of features and blocks within the GreenPAK IC.

- [1] [Go Configure Software Hub](#), Software Download, and User Guide
- [2] [AN-CM-378 DC-DC Boost & Buzzer Driver](#), GreenPAK Design File
- [3] [GreenPAK Development Tools](#), GreenPAK Development Tools Webpage
- [4] [GreenPAK Application Notes](#), GreenPAK Application Notes Webpage
- [5] SLG47105 Datasheet, Renesas Electronics

Author: Irena Zhuravchak, Renesas Electronics

3. Introduction

The HVPAK SLG47105 is a flexible configurable mixed-signal IC able to combine a Boost DC-DC Converter and a Piezo Driver in a single package with a small number of external components.

The main goal of this application note is to show how to configure HVPAK to drive a 2.5 kHz Piezo and how to create a Boost DC-DC Converter from 3 V to 13 V. The whole circuit is powered with a 3V CR2032 battery. Such a schematic can be used in devices that require short-term notifications (keychains for finding things, and others). When the push button is pressed, the DC-DC Converter boosts the voltage to 13 V which powers the Piezo Driver. Then the short pattern is played, and the circuit goes to sleep mode until the button is pressed again. When the circuit is ON – it consumes nearly 15 mA, and in sleep mode less than 50 nA. This ensures up to 800 activations on one battery!

4. Operating Principle and HVPAK Design

The DC-DC Boost & Buzzer Driver Circuit Diagram is shown in Figure 1.

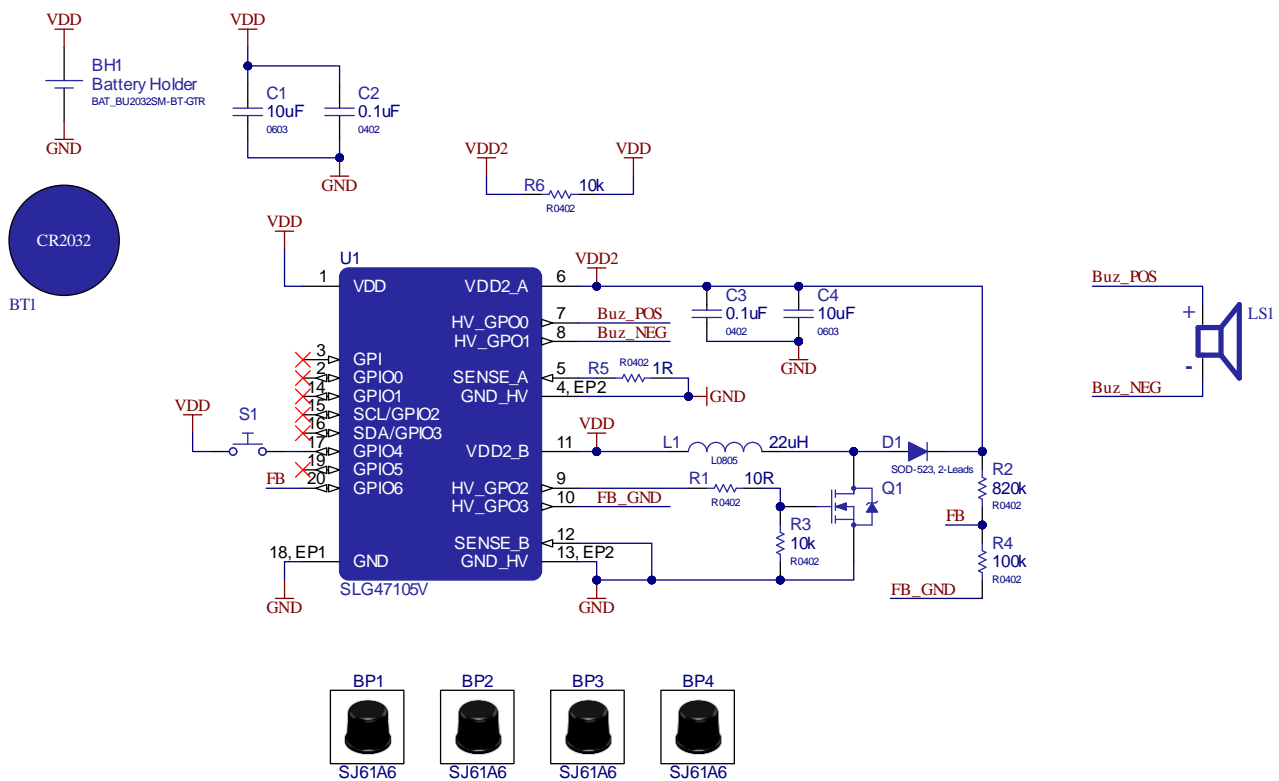


Figure 1. DC-DC Boost & Buzzer Driver Circuit Diagram

The design consists of a DC-DC Boost Converter and Buzzer Driver parts.

For the DC-DC Boost Converter, the PWM0 forms the ~197 kHz signal. The DFF1, DFF5, and DFF6 form the clock for a soft start to reduce inrush current, which can occur when the device is first turned on. Minimum and maximum duty cycles are set by Pipe Delay and CNT4/DLY4.

The VDD and VDD2_B are connected to a 3 V battery. VDD2_A is connected to Boost output. To monitor this voltage, the resistors R2 and R4 form the resistive divider with a feedback signal, which goes to PIN20 (Analog Input). This feedback voltage is compared with 1024 mV Vref by ACMP1H forming the ACMP signal which goes to the CHOP input of the PWM Chopper 0. If the VDD2 exceeds 9.5 V, the ACMP signal is HIGH and chop the formed PWM signal. The PWM Chopper 0 output goes to HV OUT CTRL1 (Half Bridge) input IN0. Then PIN 9 drives an N-FET of Boost Converter.

DC-DC Boost & Buzzer Driver

To reduce the current consumption, a resistive divider is connected to PIN 10 (Low Side ON) with a GND input.

Note: it's possible to change the ACMP1H Vref and boost the voltage up to 13 V.

The HVPAK Design is shown in [Figure 2](#).

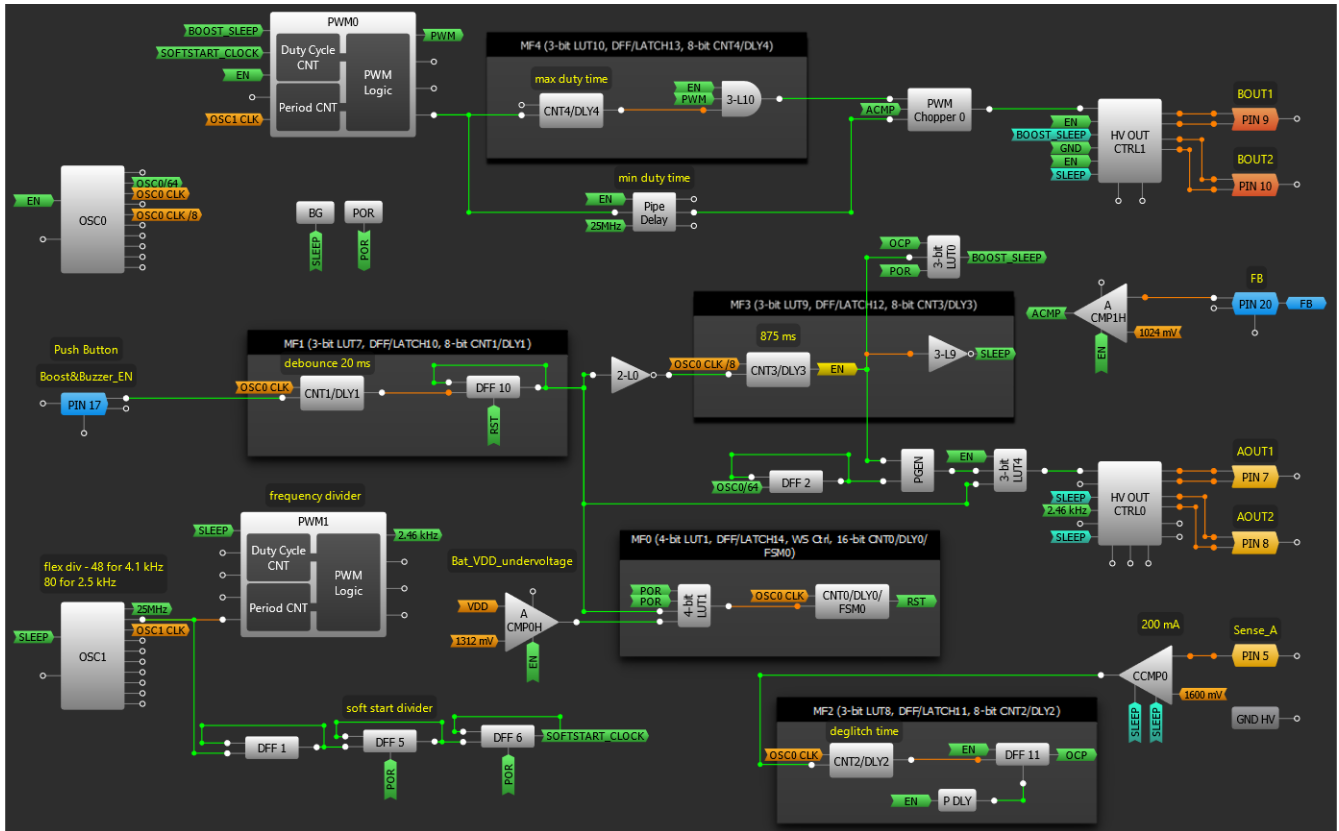


Figure 2. DC-DC Boost & Buzzer Driver HVPAK Design

The HV OUT CTRL0 (Full Bridge) drives a Piezo. PWM1 is used as a frequency divider and forms a 2.5 kHz signal (resonant frequency of a piezo), this signal comes to PH input of HV OUT CTRL0.

The 3-bit LUT4 forms the EN signal for the HV OUT CTRL0. It consists of the sound pattern signal and the general EN signal. The PGEN generates the sound pattern (01010101101011). The EN signal – the general ENABLE signal for the Duty Cycle of the whole design is HIGH for 775 ms (CNT3/DLY3 One Shot) if the button is pressed (MF1) and the VDD is higher than ~2.6 V (ACMP0H + MF0).

The 3-bit LUT9 inverts the EN signal forming the SLEEP signal to shut down the blocks when they are not used to reduce the power consumption.

The 3-bit LUT0 forms the BOOST_SLEEP signal. The Boost will power down if there is no POR signal, the SLEEP signal is HIGH, or the OCP signal is HIGH. The CCMP0 monitors the piezo current and if it exceeds 200 mA, the OCP signal is HIGH (MF2).

5. Design Testing

Channel 1 (blue / 1st line) – PIN 7 (Piezo).

Channel 2 (yellow / 2nd line) – GND (current).

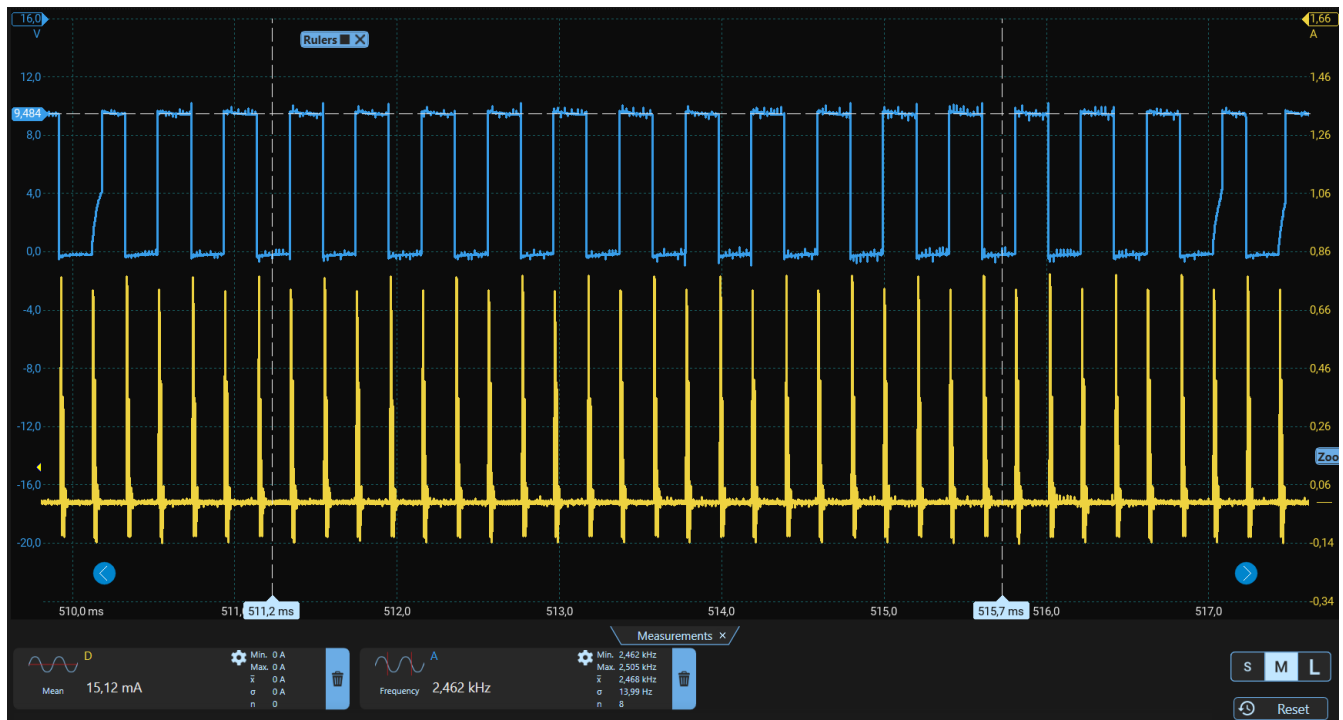


Figure 3. PIN 7 Piezo Signal (blue) & Current Consumption (yellow)

As can be seen in [Figure 3](#), the VDD2 level is 9.5 V as expected, and the Piezo frequency is 2.5 kHz. The average current consumption is 15 mA. The current in sleep mode is below 50 nA, which means up to 800 activations without replacing the battery!

6. PCB Design

The proposed Demo PCB Design is shown in Figure 4 (top) and Figure 5 (bottom). As can be seen in Figure 4, the design is so compact that it can be placed under the buzzer.

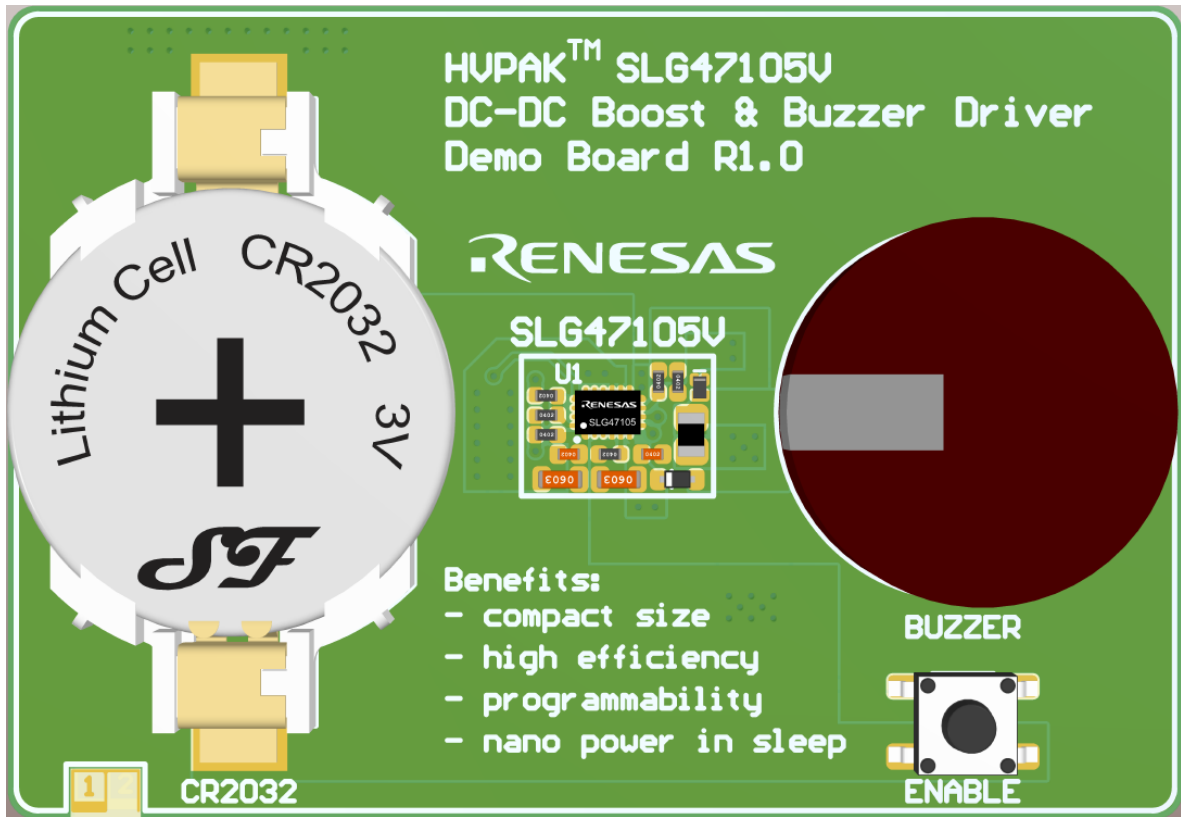


Figure 4. Boost & Buzzer Driver Demo PCB Design (Top Side)

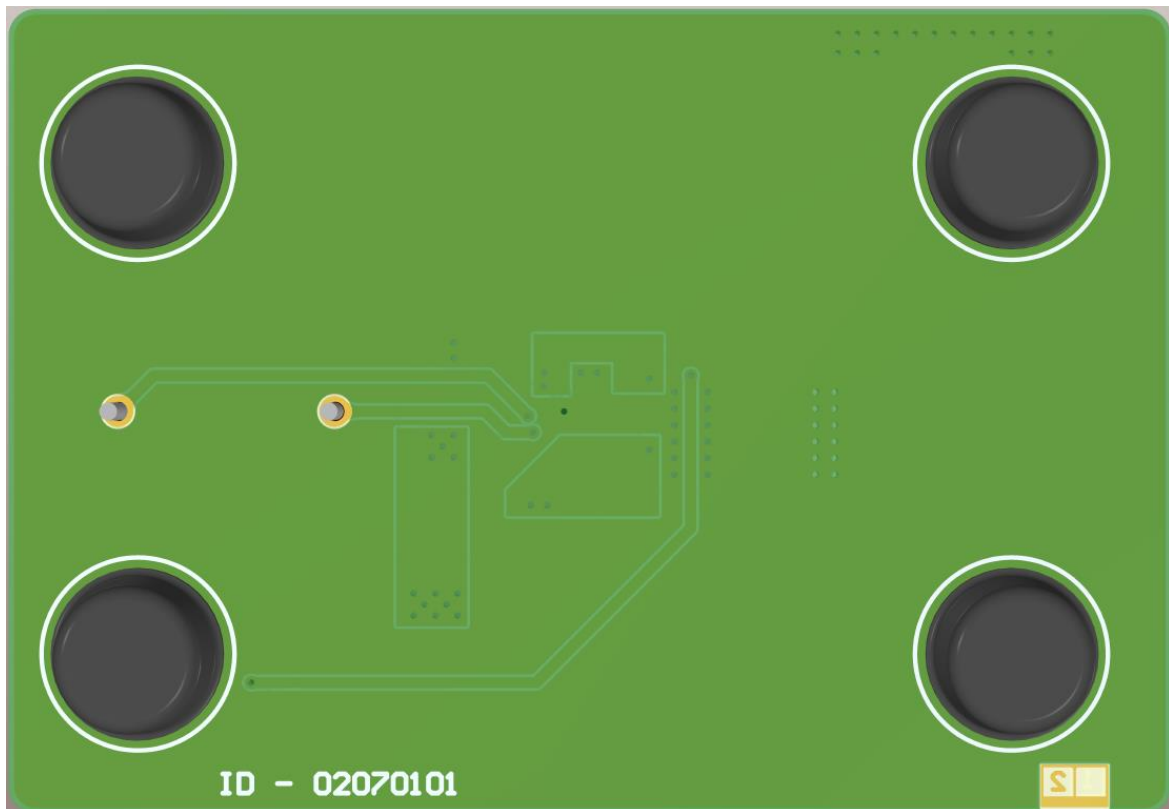


Figure 5. Boost & Buzzer Driver Demo PCB Design (Bottom Side)

7. BOM

#	Designator	Name	Manufacturer Part Number	Manufacturer	Quantity
1	BH1	Battery Holder	BU2032SM-BT-GTR	Memory Protection Devices	1
2	BP1- BP4	SJ61A6	7010334512	3M	4
3	BT1	CR2032	CR-2032L/BN	Panasonic	1
4	C1, C4	10uF 20% 25V X5R 0603	CL10A106MA8NRNC	Samsung Electro-Mechanics	2
5	C2, C3	0.1uF 10% 25V X5R 0402	CL05A104KA5NNNC	Samsung Electro-Mechanics	2
6	D1	RB521S30T1G	RB521S30T1G	ON Semiconductor	1
7	L1	22uH 220mA	MLZ2012P220WT000	TDK	1
8	LS1	SFN-17-B	SFN-17-B	Global Tone	1
9	Q1	MOSFET-N	DMN2400UFB-7	Diodes	1
10	R1	10R 1% 0402	RC0402FR-0710RL	YAGEO	1
11	R2	820k 1% 0402	RC0402FR-07820KL	YAGEO	1
12	R3, R6	10k 1% 0402	RC0402FR-0710KL	YAGEO	2
13	R4	100k 1% 0402	RC0402FR-07100KL	YAGEO	1
14	R5	1R 1% 0402	RC0402FR-071RL	Yageo	1
15	S1	Sw Tactile NO	PTS647SK38SMTR2LFS	ITT C&K	1
16	U1	SLG47105V	SLG47105V	Renesas Electronics America Inc	1

8. Conclusion

This application note describes how to configure the HVPAK SLG47105 to create a Boost & Buzzer Driver device that can work with a single 3 V CR2032 battery. With its extremely low current consumption, up to 800 activations without battery replacement are possible!

The flexibility of the internal resources allows adapting it to the needs of the customer without effort.

9. Revision History

Revision	Date	Description
1.00	June 26, 2024	Initial release

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

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